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Total Number of Pages : 02

B.TECH 1ST SEMESTER REGULAR EXAMINATIONS, DECEMBER 2017 BASICS OF ELECTRONICS Subject Code:BBSES1041

Time: 3 Hours

Max Marks : 100

The figures in the right hand margin indicate marks.

PART-A

(10X1 = 10 MARKS)

 $(15 \times 2 = 30 \text{ MARKS})$

Answer all questions.

- a. The Ripple facor value of Full wave rectifier is?
- b. The expression of β interms of α is.....?
- c. The expression I_{RMS} for HWR is?
- d. BJT acts as a switch in -----region of operation.
- e. When V_{DS}=V_{Gs}-V_T, Enhancement Mosfet is working in ------mode.
- f. Lissajous pattern is mostly used for measuring------
- g. The binary number 10101 is equivalent to decimal number
- h. For display of signal pattern voltage is applied to the horizontal plates of a CRO
- i. The form factor value of full wave rectifier is?
- j. To design Ex-OR gate, minimumno.of NAND gates are required ?

PART-B

Answer any fifteen questions from the following.

- 1. Write down the difference of Si, Ge, and GaAs
- 2. Explain in neat sketch the energy band diagram of p-n junction.
- 3. Explain the characteristics and equivalent model representation ideal diode
- 4. What are the applications of diode and in neat sketch diagram explain the concept of si diode clipping of input of 5v peak to peak to at positive 2v.
- 5. Derive the ripple factor of half wave rectifier.
- 6. Explain the output characteristics of CE configuration with neat sketch.
- 7. Derive the relationship between α , β , γ ?
- 8. Define modulation and mention the basic types of modulation?
- 9. Why BJT is called so current controlled device ?
- 10. State and explain about zener diode ?
- 11. Sketch the symbol of P-channel D-MOSFET?
- 12. What is the difference between analog and digital signal?
- 13. Find out the 1's and 2's complement of the binary number $(1011101101)_2$?
- 14. Simplify the given Boolean expression ? Y =(A'B +A'B'C')'
- 15. Bring the differences between BJT and FET ?
- 16. A Lissajous pattern on a CRO has 5horizontal tangencies & 2 vertical tangencies. The frequency of horizontal input is 1Khz. What is the frequency of vertical input?
- 17. Write down the differences between clipper and clamper circuit .

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- 18. Write down the expressions for depletion width in forward biasing and Reverse biasing od PN junction diode .
- 19. What is Shockley's equation?
- 20. Draw the circuit diagram for Sweep generator.

PART-C

 $(6 \times 5 = 30 \text{ MARKS})$

Section-i

Answer any Six questions

- 1. Derive the output current and output voltage expressions of FWR ?
- 2. Explain with suitable diagram the working operation of transistor act as an amplifier ?
- 3. Explain the PN junction under biasing.
- 4. Explain the construction of n-channel D-MOSFET ?
- 5. Find out the maxterms from the function below?
 - F(W,X,Y,Z) = (X'+Z')(W+Y)
- 6. Write the short notes on trasistor act as a switch ?
- 7. Convert the following expressions to POS form:

 $A + AB + \overline{AC}$ ii) $AB + B\overline{C} + \overline{AC}$

8. Describe the operation of any one of Full wave rectifier with the current flow direction .

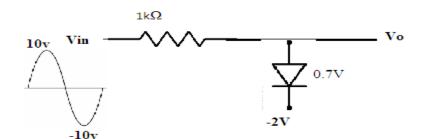
Section-ii

Answer any Two questions

(2 x 15 = 30 MARKS)

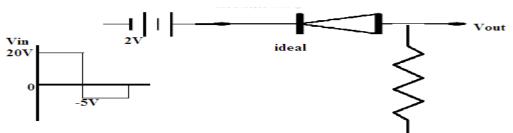
- 1. What is the need of adder circuit and Explain the Half adder and Full adder circuit with minimum number of logic gates?
- 2.A bridge type FWR uses four diodes with internal resistance of each diode $is(R_f)$ of 100 ohms if input AC signal is 220v RMS and load resistance of 1kilo ohms and the turn ratio is 9:1 .Determine
 - (i) I_{M} , I_{DC} , I_{RMS} (ii) PIV (iii) V_{DC} , V_{AC}
 - (iv) Form factor, $(v)P_{OUT}$, P_{IN} (vi)Efficiency

3.Determine the output voltage for the following diagrams:i)





ii)



4. What is standard form of Boolean expression? If the Boolean expression is represented as F (P,Q,R,S) = P'QR + RS + Q'R', Find out the standard POS form of the expression?